



74AHC1G09

SINGLE 2 INPUT POSITIVE AND GATE WITH OPEN DRAIN OUTPUT

Description

The 74AHC1G09 is a single 2-input positive AND gate with an open drain output. The device is designed for operation with a power supply range of 2.0V to 5.5V. The open-drain output can be connected to other open drain outputs to implement active-low wired-OR or active-high wired-AND functions. The gate performs the positive Boolean function:

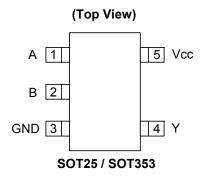
$$Y=A\bullet B \ \text{or} \ Y=\overline{A}+\overline{B}$$

A pull-up resistor is required to achieve a high output state.

Features

- Supply Voltage Range from 2.0V to 5.5V
- 8mA sink current at 5.0 V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time.
- ESD Protection per JESD 22
 - Exceeds 200-V Machine Model (A115-A)
 - Exceeds 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- SOT25 and SOT353: Assembled with "Green" Molding Compound (no Br, Sb)
 - Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
 - Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- General Purpose Logic
- · Wide array of products such as:
 - PCs, networking, notebooks, netbooks, PDAs
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box
 - Personal Navigation / GPS
 - MP3 players ,Cameras, Video Recorders

Notes:

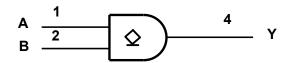
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Descriptions

Pin Name	Pin NO.	Function
Α	1	Data Input
В	2	Data Input
GND	3	Ground
Y	4	Data Output
V _{CC}	5	Supply Voltage



Logic Diagram



Functional Table

Inp	uts	Output
Α	В	Y
Н	Н	Z
L	X	L
Х	L	L

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.5 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I < 0	-20	mA
lok	Output Clamp Current (V _O < 0 or V _O > V _{CC})	±20	mA
Io	Continuous output current (V _O = 0 to V _{CC})	±25	mA
Icc	Continuous current through V _{CC}	50	mA
I _{GND}	Continuous current through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Note:

4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@TA = +25°C, unless otherwise specified.)

Symbol	F	Parameter	Min	Max	Unit
V _{CC}	Operating Voltage		2.0	5.5	V
		V _{CC} = 2V	1.5		
V_{IH}	High-Level Input Voltage	V _{CC} = 3V	2.1		V
		V _{CC} = 5.5V	3.85		
		V _{CC} = 2V		0.5	
V_{IL}	Low-Level input Voltage	V _{CC} = 3V		0.9	V
	V _{CC} = 5.5V			1.65	1
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	5.5	V
		V _{CC} = 2V		50	uA
I _{OL}	Low-Level Output Current	V_{CC} = 5V ± 0.5V		4	mA
		V _{CC} = 3V		8	MA
A+/A\/	Innut transition rise or fall rate	$V_{CC} = 3.3V \pm 0.3V$		100	no/\/
Δt/ΔV	Input transition rise or fall rate	$V_{CC} = 5V \pm 0.5V$		20	ns/V
TA	Operating free-air temperature		-40	+125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V		+25°C		-40°C t	o +85°C	-40°C to	+125°C	Unit
Symbol	Parameter	rest Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Unit
			2V			0.1		0.1		0.1	
		I _{OL} = 50μA	3V			0.1		0.1		0.1	
V_{OL}	High-level Input Voltage		4.5V			0.1		0.1		0.1	V
	Voltage	I _{OL} = 4mA	3V			0.36		0.44		0.55	
		I _{OL} = 8mA	4.5V			0.36		0.44		0.55	
II	Input Current	V _I = 5.5V or GND	0 to 5.5V			±0.1		±1		±2	μA
loz	Z-state Output Current	V _I = 5.5V or GND	0 to 5.5V			±0.25		±2.5		±10	μA
Icc	Supply Current	V _I = 5.5V or GND I _O =0	5.5V			1		10		40	μA
Ci	Input Capacitance	$V_i = V_{CC} - \text{or GND}$	5.5V		2.0	10		10		10	pF
	Thermal	SOT25			204						
θ_{JA}	Resistance Junction-to- Ambient	SOT353	(Note 6)		371						°C/W
	Thermal	SOT25			52						
$\theta_{ m JC}$	Resistance Junction-to-Case	SOT353	(Note 6)		143						°C/W

Note: 6. Test conditions for SOT25, and SOT353: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



Switching Characteristics

V_{CC} = **3.3V ±0.3** (see Figure 1)

Parameter	From	то			+25°C		-40°C to	o +85°C	-40°C to	+125°C	Unit
Parameter	(Input)	(OUTPUT)		Min	Тур	Max	Min	Max	Min	Max	Ullit
4	A or D	V	C _L = 15pF	0.6	4.6	7.5	0.6	8.5	0.6	9.0	ns
t _{pd}	A or B	Ť	C _L = 50pF	0.6	6.5	11.0	0.6	12.0	0.6	12.5	ns

 $V_{CC} = 5V \pm 0.5V$ (see Figure 1)

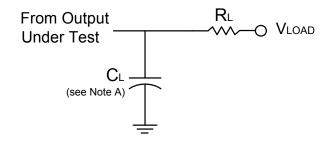
Doromotor	From	TO			+25°C		-40°C to	o +85°C	-40°C to	+125°C	Unit
Parameter	(Input)	(OUTPUT)		Min	Тур	Max	Min	Max	Min	Max	Ullit
4	A or B	V	C _L = 15pF	0.6	3.2	5.5	0.6	6.5	0.6	7.0	ns
τ _{pd}	AUID	ī	C _L = 50pF	0.6	4.6	7.5	0.6	8.0	0.6	8.5	ns

Operating Characteristics

 $T_A = +25$ °C

	Parameter	Test Conditions	V _{CC} = 5V Typ	Unit
C_pd	Power dissipation capacitance	f = 1 MHz No Load	5	pF

Parameter Measurement Information



TEST	Condition
t _{PLZ} (see Notes D and E)	V_{LOAD}
t _{PZL} (see Notes D and F)	V_{LOAD}

V	Inp	uts	V	V		В	V Δ
V _{CC}	Vı	t _r /t _f	V _M	V_{LOAD}	CL	R_L	VA
3.3V ±0.3V	V _{CC}	≤3ns	V _{CC} /2	V _{CC}	15pF	1ΚΩ	0.3V
3.3V ±0.3V	V _{CC}	≤3ns	V _{CC} /2	V _{CC}	50pF	1ΚΩ	0.3V
5V ±0.5V	V _{CC}	≤3ns	V _{CC} /2	V _{CC}	15pF	1ΚΩ	0.3V
5V ±0.5V	V _{CC}	≤3ns	V _{CC} /2	V _{CC}	50pF	1ΚΩ	0.3V



Parameter Measurement Information (cont.)

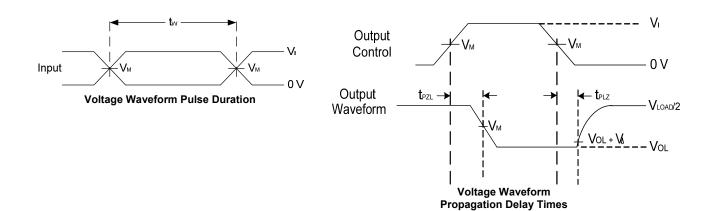


Figure 1 Load Circuit and Voltage Waveforms

Notes:

A. Includes test lead and test apparatus capacitance.
B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.
C. The inputs are measured one at a time with one transition per measurement.

D. For the open drain device t_{PLZ} and t_{PZL} are the same as t_{PD} .

E. t_{PZL} is measured at V_{M} .

F. t_{PLZ} is measured at V_{OL} + V_{Δ}



Ordering Information

T4AHC1G 09 XX - 7

Logic Device Function Package Packing

74 : Logic Prefix 09 : 2-Input W5 : SOT25 7 : Tape & Reel

AHC: 2 to 5.5V
Family
1G: One gate

AND -Gate With Open Drain Output

Part Number	Bookaga Cada	Dookaging	7" Tape	and Reel
Part Number	Package Code	Packaging	Quantity	Part Number Suffix
74AHC1G09W5-7	W5	SOT25	3000/Tape & Reel	-7
74AHC1G09SE-7	SE	SOT353	3000/Tape & Reel	-7

Marking Information

(Top View)

5 4 XX Y W X

 \underline{XX} : Identification code

<u>Y</u> : Year 0~9

 \underline{W} : Week : A $^{\sim}$ Z : 1 $^{\sim}$ 26 week;

SE: SOT353

a~z: 27~52 week; z represents 52 and 53 week

 \underline{X} : A $^{\sim}$ Z: Internal code

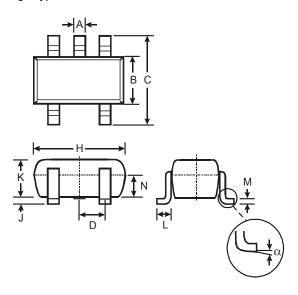
Part Number	Package	Identification Code
74AHC1G09W5	SOT25	YN
74AHC1G09SE	SOT353	YN



Package Outline Dimensions (All dimensions in mm.)

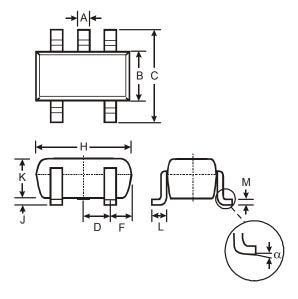
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

(1) Package Type: SOT25



SOT25				
Dim	Min	Max	Тур	
Α	0.35	0.50	0.38	
В	1.50	1.70	1.60	
С	2.70	3.00	2.80	
D	_		0.95	
Н	2.90	3.10	3.00	
J	0.013	0.10	0.05	
K	1.00	1.30	1.10	
L	0.35	0.55	0.40	
M	0.10	0.20	0.15	
N	0.70	0.80	0.75	
α	0°	8°	_	
All Dimensions in mm				

(2) Package Type: SOT353



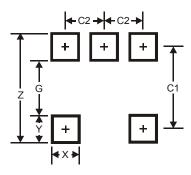
SOT353			
Dim	Min	Max	
Α	0.10	0.30	
В	1.15	1.35	
C	2.00	2.20	
D	0.65 Typ		
F	0.40	0.45	
Η	1.80	2.20	
J	0	0.10	
K	0.90	1.00	
L	0.25	0.40	
М	0.10	0.22	
α	0°	8°	
All Dimensions in mm			



Suggested Pad Layout

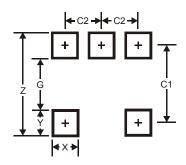
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(1) Package Type: SOT25



Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

(2) Package Type: SOT353



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Y	0.6
C1	1.9
C2	0.65



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2013, Diodes Incorporated

www.diodes.com